

# SN74AVC16835 18-BIT UNIVERSAL BUS DRIVER WITH 3-STATE OUTPUTS

SCES168H – DECEMBER 1998 – REVISED FEBRUARY 2000

- Member of the Texas Instruments *Widebus*™ Family
- *EPIC*™ (Enhanced-Performance Implanted CMOS) Submicron Process
- *DOC*™ (Dynamic Output Control) Circuit Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- Dynamic Drive Capability Is Equivalent to Standard Outputs With  $I_{OH}$  and  $I_{OL}$  of  $\pm 24$  mA at 2.5-V  $V_{CC}$
- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Ideal for Use in PC133 Registered DIMM Applications
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- Package Options Include Plastic Thin Shrink Small-Outline (DGG) and Thin Very Small-Outline (DGV) Packages

## description

A Dynamic Output Control (DOC) circuit is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical  $V_{OL}$  vs  $I_{OL}$  and  $V_{OH}$  vs  $I_{OH}$  curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to TI application reports *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC)™ Circuitry Technology and Applications*, literature number SCEA009.

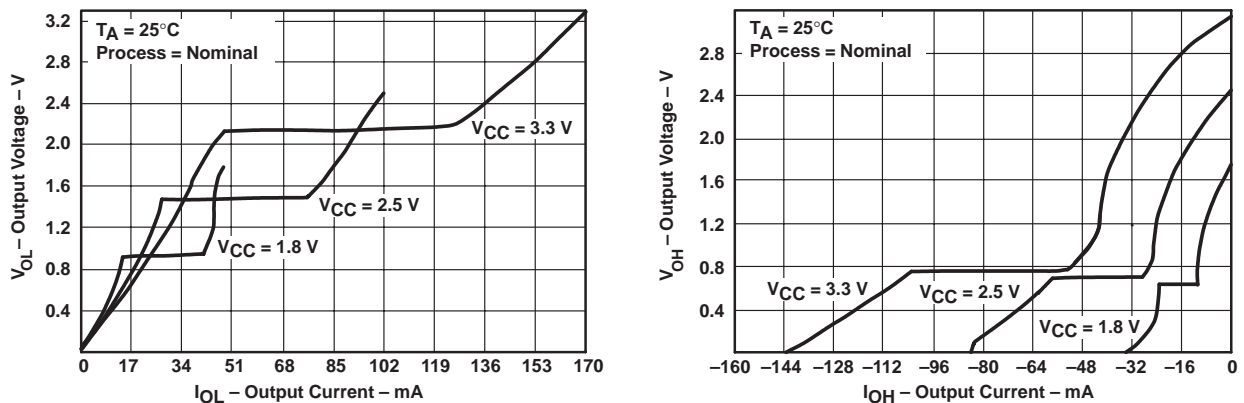


Figure 1. Output Voltage vs Output Current

This 18-bit universal bus driver is operational at 1.2-V to 3.6-V  $V_{CC}$ , but is designed specifically for 1.65-V to 3.6-V  $V_{CC}$  operation.

Data flow from A to Y is controlled by the output-enable ( $\overline{OE}$ ) input. The device operates in the transparent mode when the latch-enable (LE) input is high. The A data is latched if the clock (CLK) input is held at a high or low logic level. If LE is low, the A data is stored in the latch/flip-flop on the low-to-high transition of CLK. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



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### WITH 3-STATE OUTPUTS

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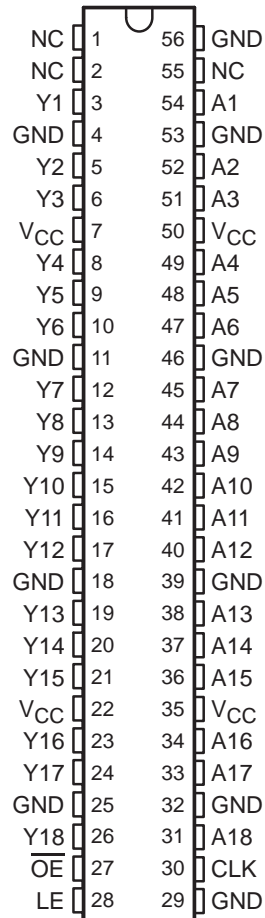
#### description (continued)

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SN74AVC16835 is characterized for operation from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

#### terminal assignments

DGG OR DGV PACKAGE  
(TOP VIEW)



NC – No internal connection

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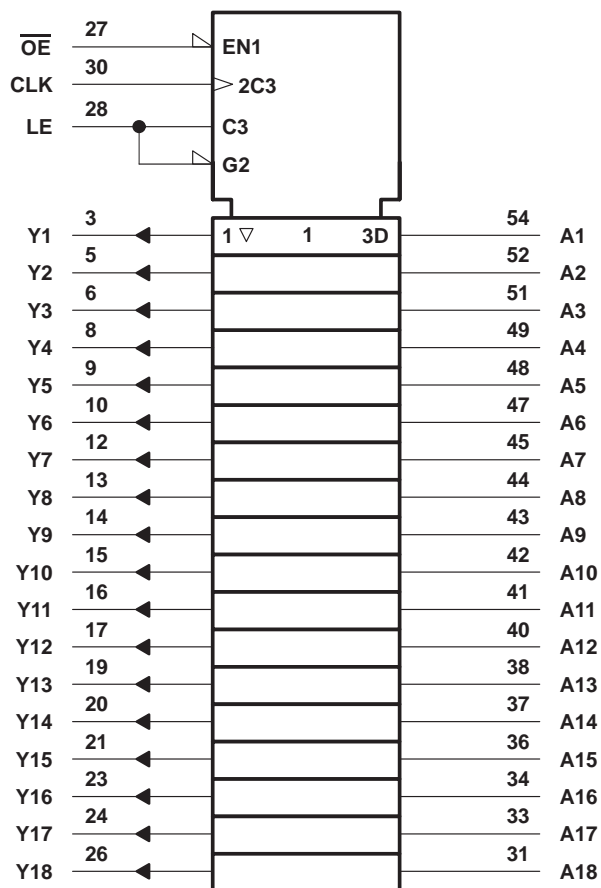
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**FUNCTION TABLE**  
(each universal bus driver)

INPUTS				OUTPUT
$\overline{OE}$	LE	CLK	A	Y
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	↑	L	L
L	L	↑	H	H
L	L	L or H	X	$Y_0^\dagger$

† Output level before the indicated steady-state input conditions were established, provided that CLK is high before LE goes low

## logic symbol‡



‡ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.





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**recommended operating conditions (see Note 4)**

		MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage	Operating	1.4	3.6	V
		Data retention only	1.2		
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub>		V
		V <sub>CC</sub> = 1.4 V to 1.6 V	0.65 × V <sub>CC</sub>		
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>		
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7		
		V <sub>CC</sub> = 3 V to 3.6 V	2		
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 1.2 V	GND		V
		V <sub>CC</sub> = 1.4 V to 1.6 V	0.35 × V <sub>CC</sub>		
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.35 × V <sub>CC</sub>		
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.7		
		V <sub>CC</sub> = 3 V to 3.6 V	0.8		
V <sub>I</sub>	Input voltage	0	3.6	V	
V <sub>O</sub>	Output voltage	Active state	0	V <sub>CC</sub>	V
		3-state	0	3.6	
I <sub>OHS</sub>	Static high-level output current†	V <sub>CC</sub> = 1.4 V to 1.6 V	–2		mA
		V <sub>CC</sub> = 1.65 V to 1.95 V	–4		
		V <sub>CC</sub> = 2.3 V to 2.7 V	–8		
		V <sub>CC</sub> = 3 V to 3.6 V	–12		
I <sub>OLS</sub>	Static low-level output current†	V <sub>CC</sub> = 1.4 V to 1.6 V	2		mA
		V <sub>CC</sub> = 1.65 V to 1.95 V	4		
		V <sub>CC</sub> = 2.3 V to 2.7 V	8		
		V <sub>CC</sub> = 3 V to 3.6 V	12		
Δt/Δv	Input transition rise or fall rate	V <sub>CC</sub> = 1.4 V to 3.6 V		5	ns/V
T <sub>A</sub>	Operating free-air temperature	–40	85	°C	

† Dynamic drive capability is equivalent to standard outputs with I<sub>OH</sub> and I<sub>OL</sub> of ±24 mA at 2.5-V V<sub>CC</sub>. See Figure 1 for V<sub>OL</sub> vs I<sub>OL</sub> and V<sub>OH</sub> vs I<sub>OH</sub> characteristics. Refer to TI application reports *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC™) Circuitry Technology and Applications*, literature number SCEA009.

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to TI application report *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER		TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP†	MAX	UNIT
V <sub>OH</sub>		I <sub>OHS</sub> = -100 μA,	1.4 V to 3.6 V	V <sub>CC</sub> -0.2			V
		I <sub>OHS</sub> = -2 mA, V <sub>IH</sub> = 0.91 V	1.4 V	1.05			
		I <sub>OHS</sub> = -4 mA, V <sub>IH</sub> = 1.07 V	1.65 V	1.2			
		I <sub>OHS</sub> = -8 mA, V <sub>IH</sub> = 1.7 V	2.3 V	1.75			
		I <sub>OHS</sub> = -12 mA, V <sub>IH</sub> = 2 V	3 V	2.3			
V <sub>OL</sub>		I <sub>OLS</sub> = 100 μA	1.4 V to 3.6 V			0.2	V
		I <sub>OLS</sub> = 2 mA, V <sub>IL</sub> = 0.49 V	1.4 V			0.4	
		I <sub>OLS</sub> = 4 mA, V <sub>IL</sub> = 0.57 V	1.65 V			0.45	
		I <sub>OLS</sub> = 8 mA, V <sub>IL</sub> = 0.7 V	2.3 V			0.55	
		I <sub>OLS</sub> = 12 mA, V <sub>IL</sub> = 0.8 V	3 V			0.7	
I <sub>I</sub>	Control inputs	V <sub>I</sub> = V <sub>CC</sub> or GND	3.6 V			±2.5	μA
I <sub>off</sub>		V <sub>I</sub> or V <sub>O</sub> = 3.6 V	0			±10	μA
I <sub>OZ</sub>		V <sub>O</sub> = V <sub>CC</sub> or GND, $\overline{OE}$ = V <sub>CC</sub>	3.6 V			±10	μA
I <sub>CC</sub>		V <sub>I</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0	3.6 V			40	μA
C <sub>i</sub>	CLK input	V <sub>I</sub> = V <sub>CC</sub> or GND	2.5 V			4	pF
			3.3 V			4	
	Control inputs	V <sub>I</sub> = V <sub>CC</sub> or GND	2.5 V			4	
			3.3 V			4	
	Data inputs	V <sub>I</sub> = V <sub>CC</sub> or GND	2.5 V			2.5	
			3.3 V			2.5	
C <sub>o</sub>	Outputs	V <sub>O</sub> = V <sub>CC</sub> or GND	2.5 V			6.5	pF
			3.3 V			6.5	

† Typical values are measured at T<sub>A</sub> = 25°C.

**timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 2 through 5)**

		V <sub>CC</sub> = 1.2 V		V <sub>CC</sub> = 1.5 V ± 0.1 V		V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock frequency					150		150		150		MHz
t <sub>w</sub>	Pulse duration	LE high				3.3		3.3		3.3		ns
		CLK high or low				3.3		3.3		3.3		
t <sub>su</sub>	Setup time	Data before CLK↑		1	0.9	0.7		0.7		0.7		ns
		Data before LE↓	CLK high	1.7	1.6	1.2		0.8		0.8		
			CLK low	2	0.9	0.7		0.5		0.5		
t <sub>h</sub>	Hold time	Data after CLK↑		1.5	1.3	1		0.9		1.3		ns
		Data after LE↓	CLK high	3.2	2.4	2		1.7		1.6		
			CLK low	2.8	2.1	1.7		1.5		1.4		



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switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 2 through 5)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> = 1.5 V ± 0.1 V		V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>						150		150		150		MHz
t <sub>pd</sub>	A	Y	4.5	1.2	6.2	1.3	5.5	1	3.1	0.9	2.5	ns
	LE		6.2	1.6	9.4	1.3	7.2	1.1	4.7	0.9	3.8	
	CLK		5.2	1.6	7.8	1.5	6	1	3.7	0.8	3.1	
t <sub>en</sub>	$\overline{\text{OE}}$	Y	7.1	2.4	10.2	2.2	8.8	1.5	6.7	1.2	6.2	ns
t <sub>dis</sub>	$\overline{\text{OE}}$	Y	6.9	2.2	10.3	2	8.4	1.2	5.3	1.1	5.3	ns

switching characteristics, T<sub>A</sub> = 0°C to 85°C, C<sub>L</sub> = 0 pF†

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 3.3 V ± 0.15 V		UNIT
			MIN	MAX	
t <sub>pd</sub>	A	Y	0.6	1.3	ns
	CLK		0.7	1.5	

† Texas Instruments SPICE simulation data

operating characteristics, T<sub>A</sub> = 25°C

PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	UNIT
			TYP	TYP	TYP	
C <sub>pd</sub>	Power dissipation capacitance	C <sub>L</sub> = 0, f = 10 MHz	45	48	52	pF
	Outputs enabled		23	25	28	
	Outputs disabled					

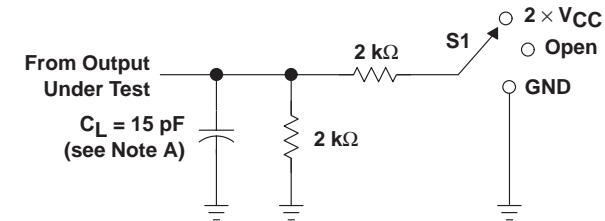


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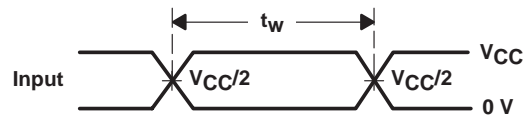
**PARAMETER MEASUREMENT INFORMATION**

$V_{CC} = 1.2\text{ V AND } 1.5\text{ V} \pm 0.1\text{ V}$

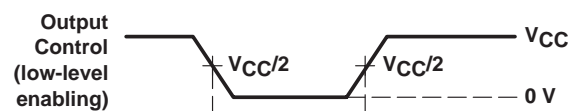
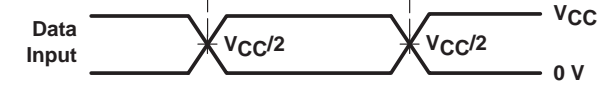


**LOAD CIRCUIT**

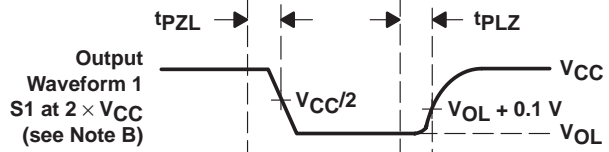
TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	2 $\times$ $V_{CC}$
$t_{PHZ}/t_{PZH}$	GND



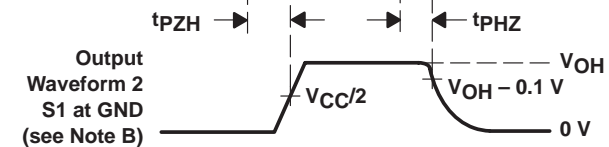
**VOLTAGE WAVEFORMS PULSE DURATION**



**VOLTAGE WAVEFORMS SETUP AND HOLD TIMES**



**VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES**



**VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES**

- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r \leq 2\text{ ns}$ ,  $t_f \leq 2\text{ ns}$ .
  - D. The outputs are measured one at a time with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

**Figure 2. Load Circuit and Voltage Waveforms**

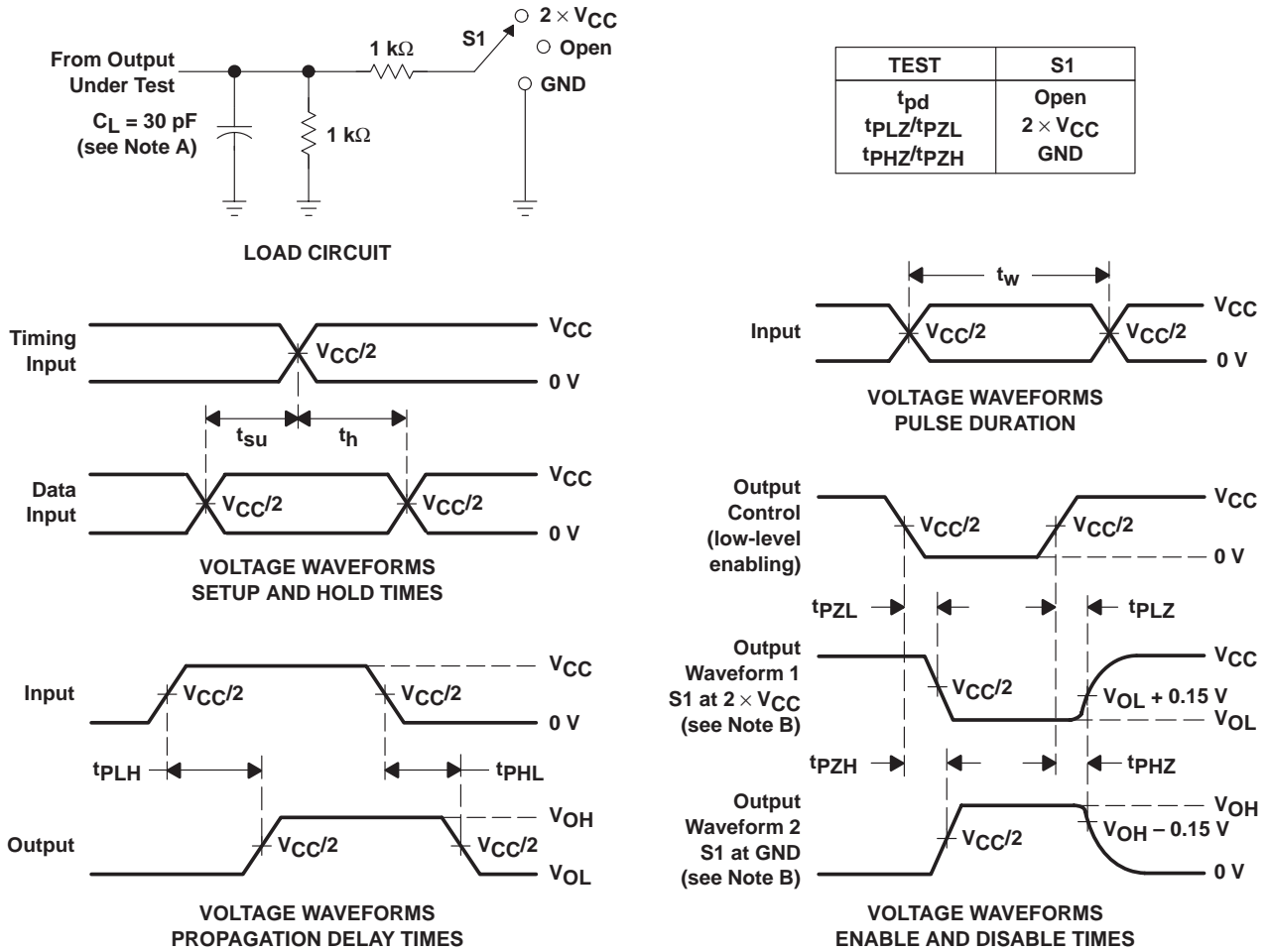


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**PARAMETER MEASUREMENT INFORMATION**

$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$



- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50\ \Omega$ ,  $t_r \leq 2\text{ ns}$ ,  $t_f \leq 2\text{ ns}$ .
  - D. The outputs are measured one at a time with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

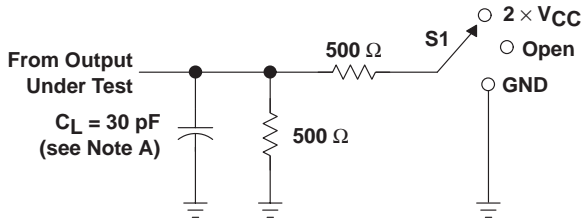
**Figure 3. Load Circuit and Voltage Waveforms**

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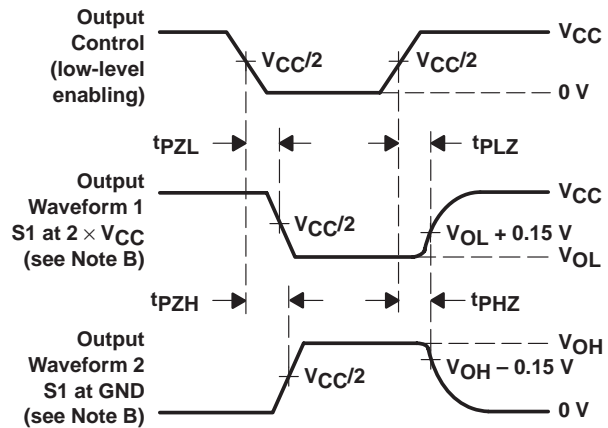
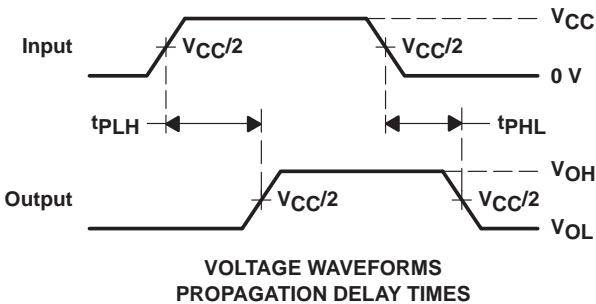
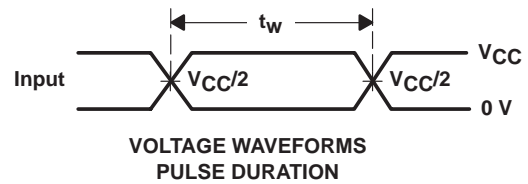
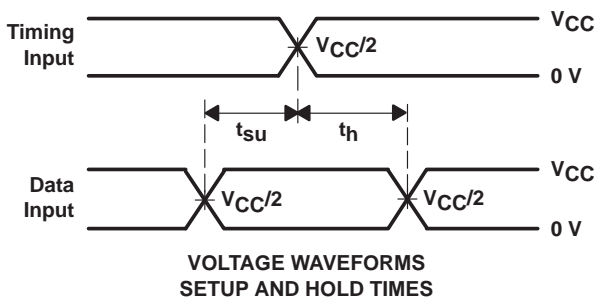
**PARAMETER MEASUREMENT INFORMATION**

$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$



**LOAD CIRCUIT**

TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	2 $\times V_{CC}$
$t_{PHZ}/t_{PZH}$	GND

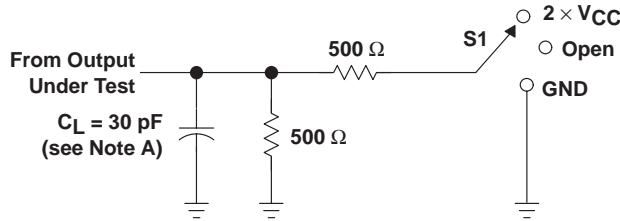


- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r \leq 2\text{ ns}$ ,  $t_f \leq 2\text{ ns}$ .
  - D. The outputs are measured one at a time with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

**Figure 4. Load Circuit and Voltage Waveforms**

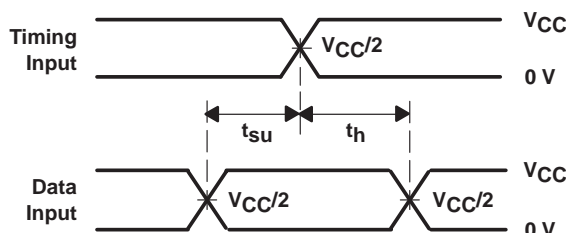
PARAMETER MEASUREMENT INFORMATION

$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$

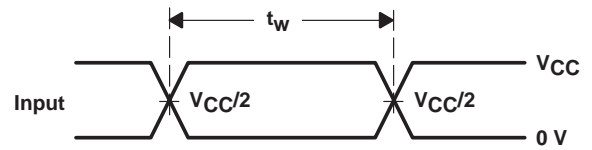


LOAD CIRCUIT

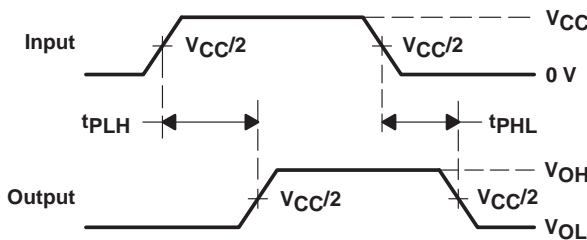
TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	2 $\times$ $V_{CC}$
$t_{PHZ}/t_{PHZ}$	GND



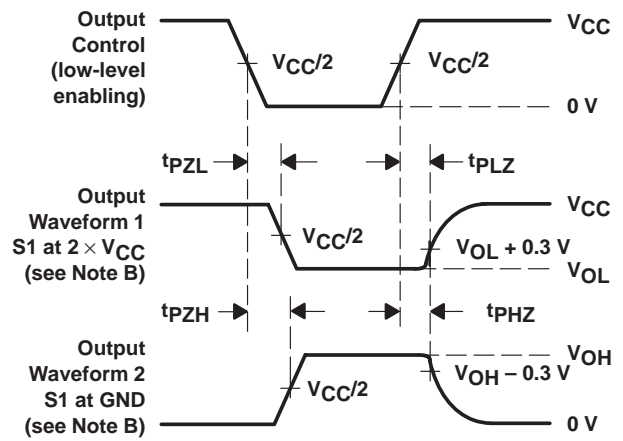
VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES

- NOTES:
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  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r \leq 2\text{ ns}$ ,  $t_f \leq 2\text{ ns}$ .
  - The outputs are measured one at a time with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 5. Load Circuit and Voltage Waveforms

## **IMPORTANT NOTICE**

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